

Electric and Magnetic Fields in Matter

Static Fields

Time-Dependent Fields

Stationary Media

Moving Media

Basic Idea

The applied fields induce internal alignment

This alignment produces an additional field

Formalism

Introduce fields that do not include the fields due to alignment

free charges

free currents

bound charges

bound currents

Introduce polarization due to the bound charges and currents

Table 30-2**THREE ELECTRIC VECTORS**

Name	Symbol	Associated with	Boundary Condition
Electric field strength	E	All charges	Tangential component continuous
Electric displacement	D	Free charges only	Normal component continuous
Polarization (electric dipole moment per unit volume)	P	Polarization charges only	Vanishes in a vacuum
Defining equation for E		$\mathbf{F} = q\mathbf{E}$	Eq. 27-2
General relation among the three vectors		$\mathbf{D} = \epsilon_0\mathbf{E} + \mathbf{P}$	Eq. 30-21
Gauss's law when dielectric media are present		$\oint \mathbf{D} \cdot d\mathbf{S} = q$ (q = free charge only)	Eq. 30-24
Empirical relations for certain dielectric materials *		$\mathbf{D} = \kappa\epsilon_0\mathbf{E}$ $\mathbf{P} = (\kappa - 1)\epsilon_0\mathbf{E}$	Eq. 30-22 Eq. 30-23

* Generally true, with κ independent of \mathbf{E} , except for certain materials called *ferroelectrics*; see footnote on page 758.

Table 37-1

THREE MAGNETIC VECTORS

Name	Symbol	Associated with	Boundary Condition
Magnetic induction	B	All currents	Normal component continuous
Magnetic field strength	H	True currents only	Tangential component continuous †
Magnetization (magnetic dipole moment per unit volume)	M	Magnetization currents only	Vanishes in a vacuum
Defining equations for B		$\mathbf{F} = q\mathbf{v} \times \mathbf{B}$ or $= i\mathbf{l} \times \mathbf{B}$	Eq. 33-3a Eq. 33-6a
General relation among the three vectors		$\mathbf{B} = \mu_0\mathbf{H} + \mu_0\mathbf{M}$	Eq. 37-26
Ampère's law when magnetic materials are present		$\oint \mathbf{H} \cdot d\mathbf{l} = i$ (i = true current only)	Eq. 37-27
Empirical relations for certain magnetic materials *		$\mathbf{B} = \kappa_m\mu_0\mathbf{H}$ $\mathbf{M} = (\kappa_m - 1)\mathbf{H}$	Eq. 37-29 Eq. 37-30

* For paramagnetic and diamagnetic materials only, if κ_m is to be independent of **H**.

† Assuming no true currents exist at the boundary.

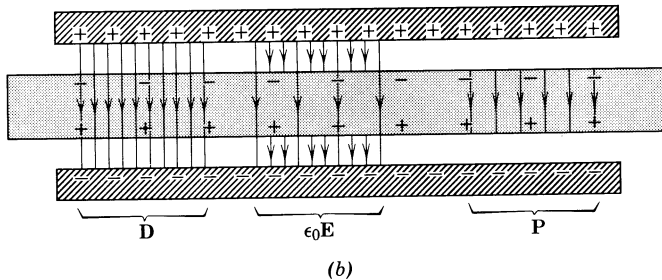
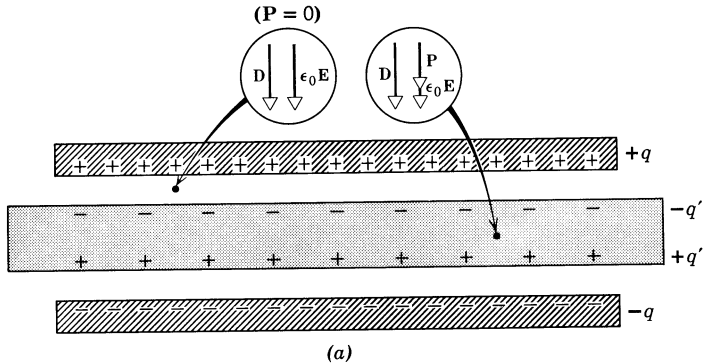


Fig. 30-13 (a) Showing \mathbf{D} , $\epsilon_0\mathbf{E}$, and \mathbf{P} in the dielectric (*upper right*) and in the gap (*upper left*) for a parallel-plate capacitor. (b) Showing samples of the lines associated with \mathbf{D} (free charge), $\epsilon_0\mathbf{E}$ (all charges), and \mathbf{P} (polarization charge).

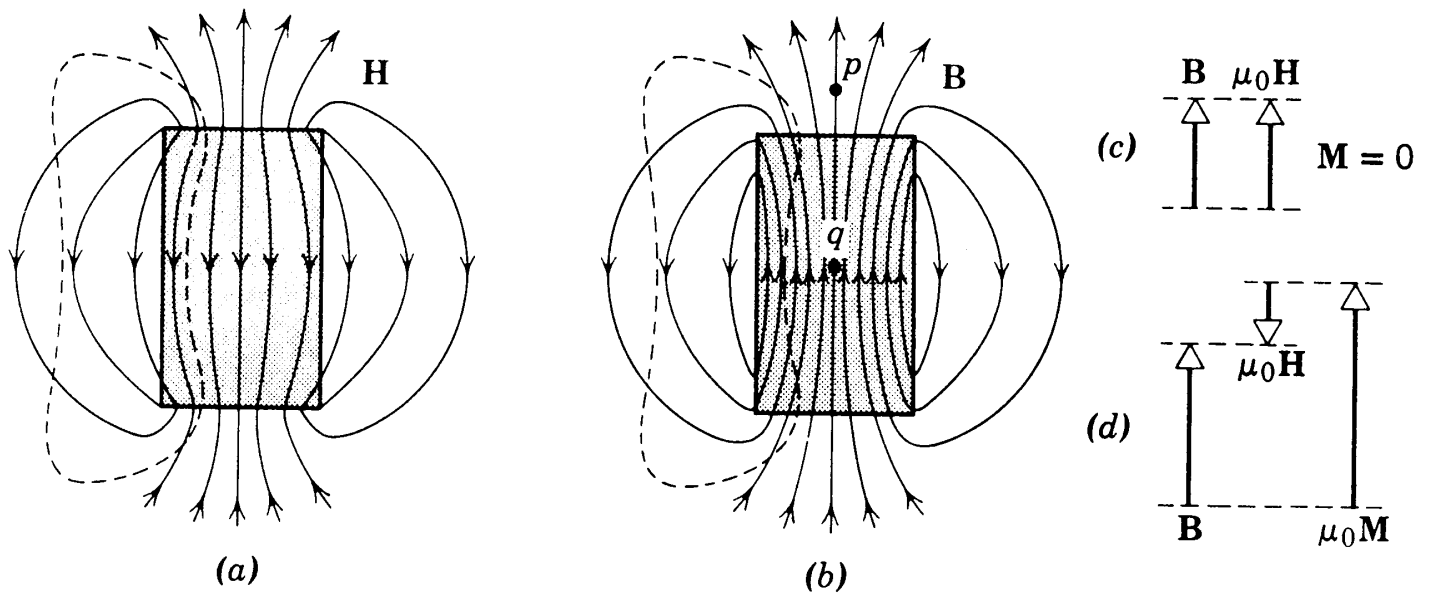


Fig. 37-22 (a) The lines of \mathbf{H} and (b) the lines of \mathbf{B} for a permanent magnet. Note that the lines of \mathbf{H} change direction at the boundary. The closed dashed curves are paths of integration around which Ampère's law may be applied. The relation $\mathbf{B} = \mu_0 \mathbf{H} + \mu_0 \mathbf{M}$ is shown to be satisfied for (c) a particular outside point p and (d) a particular inside point q .

BASIC EQUATIONS OF ELECTRODYNAMICS

Maxwell's Equations

In general :

$$\left\{ \begin{array}{l} \nabla \cdot \mathbf{E} = \frac{1}{\epsilon_0} \rho \\ \nabla \times \mathbf{E} = -\frac{\partial \mathbf{B}}{\partial t} \\ \nabla \cdot \mathbf{B} = 0 \\ \nabla \times \mathbf{B} = \mu_0 \mathbf{J} + \mu_0 \epsilon_0 \frac{\partial \mathbf{E}}{\partial t} \end{array} \right.$$

In matter :

$$\left\{ \begin{array}{l} \nabla \cdot \mathbf{D} = \rho_f \\ \nabla \times \mathbf{E} = -\frac{\partial \mathbf{B}}{\partial t} \\ \nabla \cdot \mathbf{B} = 0 \\ \nabla \times \mathbf{H} = \mathbf{J}_f + \frac{\partial \mathbf{D}}{\partial t} \end{array} \right.$$

Auxiliary Fields

Definitions :

$$\left\{ \begin{array}{l} \mathbf{D} = \epsilon_0 \mathbf{E} + \mathbf{P} \\ \mathbf{H} = \frac{1}{\mu_0} \mathbf{B} - \mathbf{M} \end{array} \right.$$

Linear media :

$$\left\{ \begin{array}{l} \mathbf{P} = \epsilon_0 \chi_e \mathbf{E}, \quad \mathbf{D} = \epsilon \mathbf{E} \\ \mathbf{M} = \chi_m \mathbf{H}, \quad \mathbf{H} = \frac{1}{\mu} \mathbf{B} \end{array} \right.$$

SO FAR: \vec{E} and \vec{B} in vacuum
 quasi-static limit

THIS WEEK: \vec{E} in matter
 DIELECTRICS

NEXT WEEK: \vec{B} in matter
 DIAMAGNETS

FINALLY: COMPLETE MAXWELL EQUATIONS

AUXILIARY FIELDS

$$\vec{D} = \epsilon_0 \vec{E} + \vec{P}$$

$$\vec{H} = \frac{1}{\mu_0} \vec{B} - \vec{M}$$

LINEAR MEDIA

$$\vec{P} = \chi_e (\epsilon_0 \vec{E})$$

$$\vec{M} = \chi_m \vec{H}$$

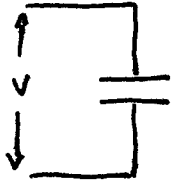
$$\vec{D} = \epsilon_0 \vec{E}$$

$$\vec{H} = \frac{1}{\mu} \vec{B}$$

WHICH PAIR IS FUNDAMENTAL? \vec{E} and \vec{B} ?
 \vec{D} and \vec{H} ?

FREYMAN'S VIEW

FARADAY FOUND



$$C = \epsilon_0 \frac{A}{d}$$

ϵ_0 OF VACUUM

$$C = \epsilon \frac{A}{d}$$

ϵ OF MEDIUM

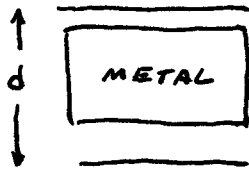
$$\epsilon > \epsilon_0$$

MORE CAPACITANCE!

MORE STORED ENERGY!

FARADAY ASKED WHY?

NEW DECREASE GAP \Rightarrow MORE CAPACITANCE



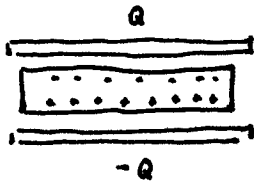
$$C = \epsilon_0 \frac{A}{d}$$

$$C' = \epsilon_0 \frac{A}{d'}$$

$\epsilon \Rightarrow$ WANT INSULATOR WITH CONDUCTORS INSIDE

HOW CAN THAT BE?

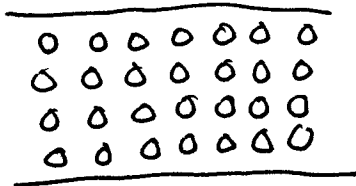
SUPPOSE WE PUT A SLAB OF METAL



$$C' = \frac{\epsilon_0 A}{d'}$$

$$d' < d \Rightarrow C' > C$$

SO FARADAY HYPOTHESIZED



conducting spheres
inside an insulator

~~induced charge in the~~

Induced charge separation in the spheres

Spheres separated by insulator

\Rightarrow Atoms are perfect conductors

Atoms are separated by an insulator

We now know 2 EFFECTS

Charge separation $\begin{cases} \rightarrow$ polarization FARADAY'S IDEA \\ \rightarrow reorientation of dipoles \end{cases}

First principles

[edit]

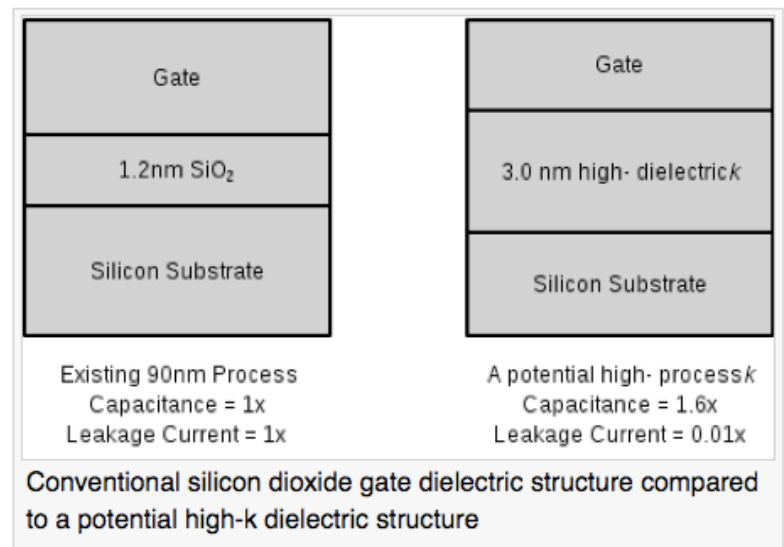
The gate oxide in a MOSFET can be modeled as a parallel plate capacitor. Ignoring quantum mechanical and depletion effects from the Si substrate and gate, the capacitance C of this parallel plate capacitor is given by

$$C = \frac{\kappa \epsilon_0 A}{t}$$

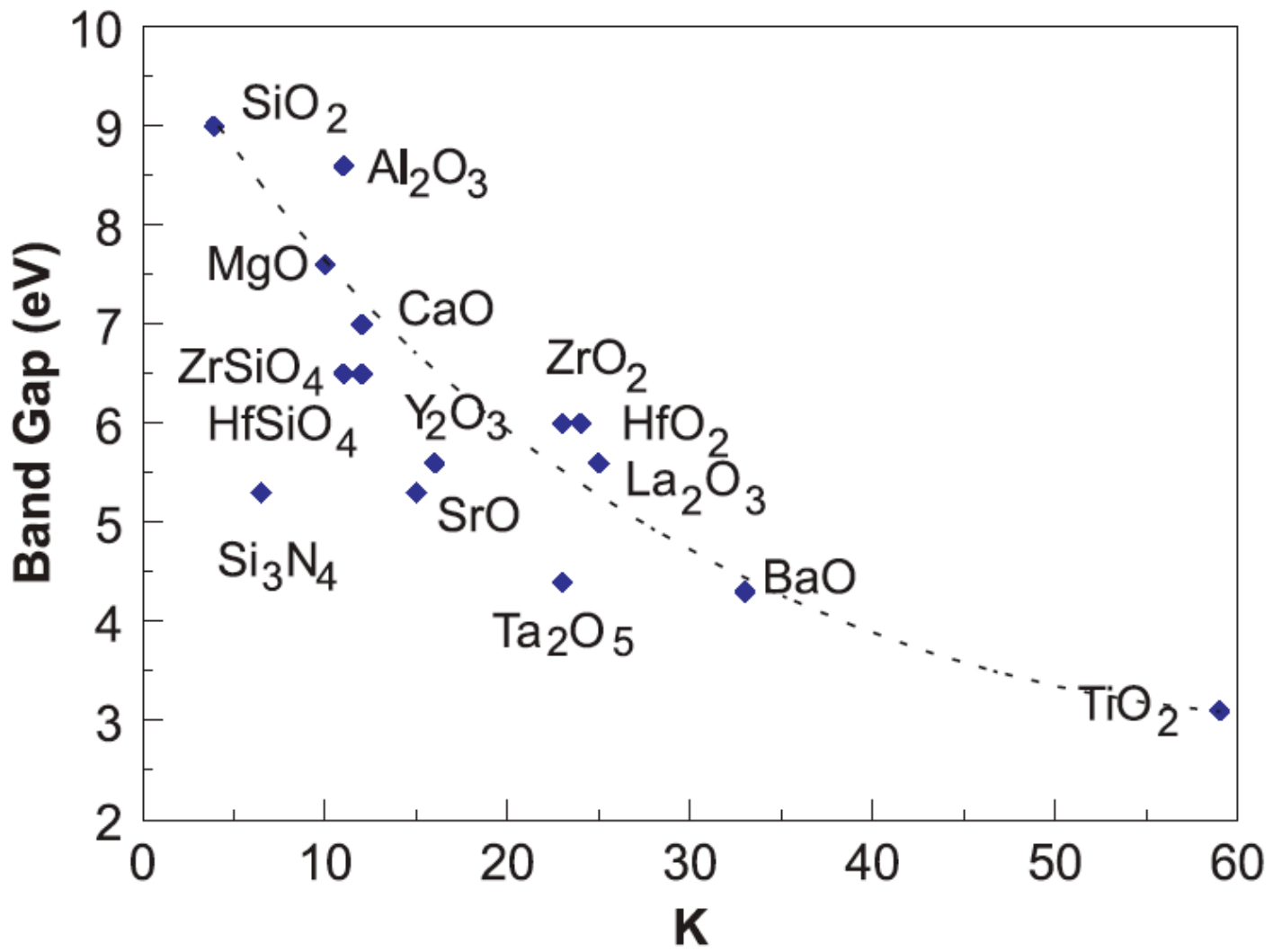
Where

- A is the capacitor area
- κ is the relative dielectric constant of the material (3.9 for silicon dioxide)
- ϵ_0 is the permittivity of free space
- t is the thickness of the capacitor oxide insulator

Since leakage limitation constrains further reduction of t , an alternative method to increase gate capacitance is alter κ by replacing silicon dioxide with a high- κ material. In such a scenario, a thicker gate layer might be used which can reduce the leakage current flowing through the structure as well as improving the gate dielectric reliability.



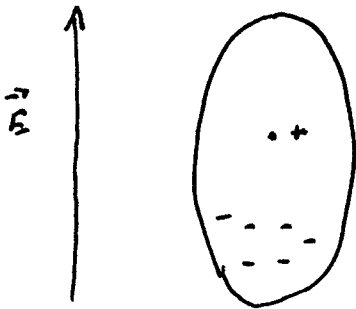
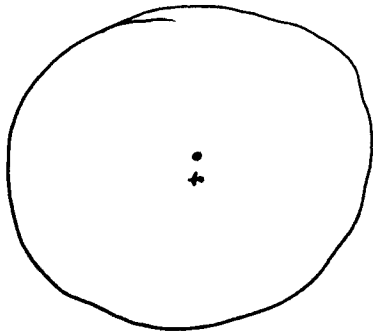
Gate



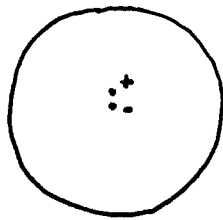
POLARIZABILITY OF ATOMS

INDUCED DIPOLES

~ induced dipoles in Faraday's metal spheres.



ACTUALLY THE DISTORTION IS EXTREMELY SMALL



SUPERPOSITION : POSITIVE POINT CHARGE
NEGATIVE CHARGED SPHERE

FIELD OUTSIDE

•+
•-

Our old friend the dipole!

INDUCED DIPOLE MOMENT

$$\vec{p} = q \vec{r}$$

INDUCED POLARIZATION VECTOR

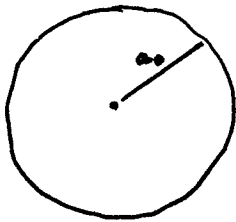
$$\vec{P} = n \vec{p} = n q \vec{r}$$

↑
atoms per unit volume

FOR SMALL FIELDS (linear dielectrics)

$$\vec{p} = \alpha \vec{E}$$

↑
atomic polarizability



$$E_a = \frac{e}{a_0^2}$$

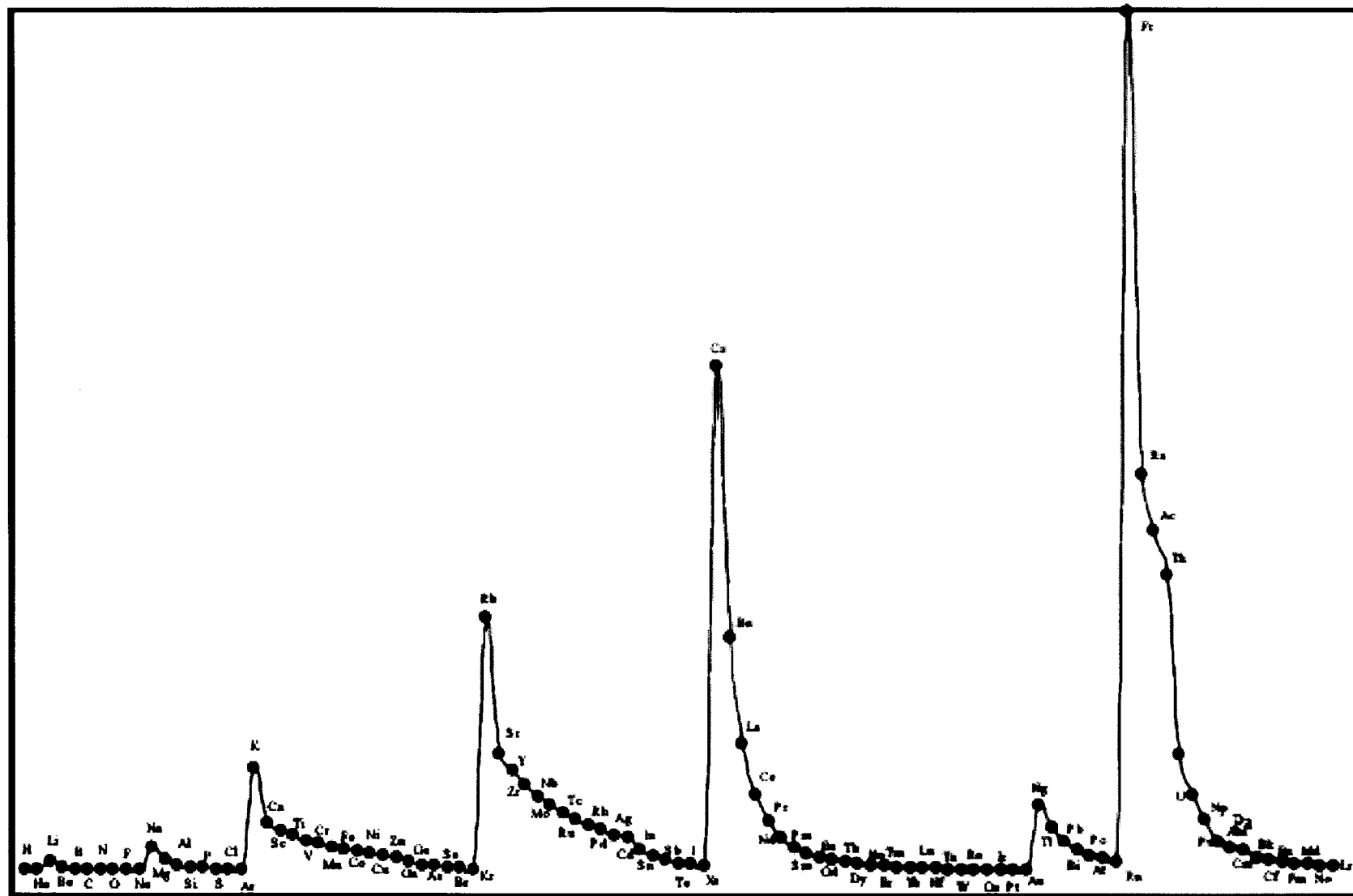
$$\text{DISTORTION} \propto \frac{E_{\text{atb}}}{E_a} = \frac{E}{(e/a_0^2)}$$

ATOMIC FIELDS: 3×10^{11} V/m

EXTERNAL FIELDS: 3×10^8 V/m

⇒ DISTORTIONS ARE SMALL

Atomic polarizability

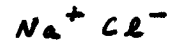


Atomic number.

SECOND EFFECT
PERMANENT DIPOLE MOMENTS

NaCl

ionic linear



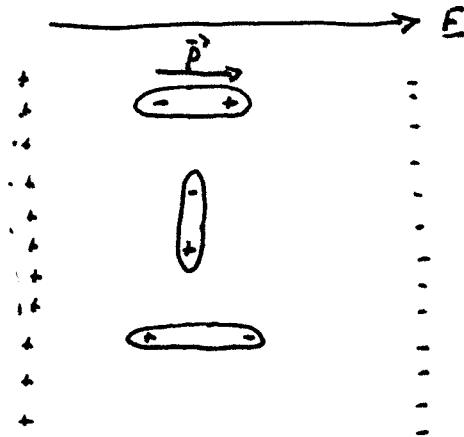
HCl

H2O

covalent ~~is~~ not linear



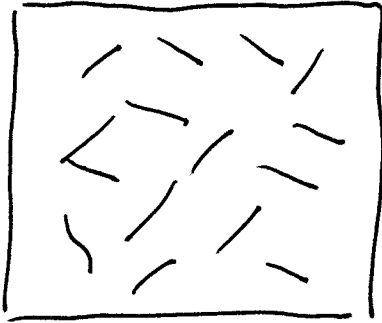
PUT A DIPOLE IN A FIELD



$$U = -\vec{p} \cdot \vec{E}$$

$$\tau = \vec{p} \times \vec{E}$$

MOLECULAR DIELECTRICS



RANDOM
DIPOLES



APPLY
FIELD

DIPOLES WANT TO ALIGN
WITH THE APPLIED FIELD

IF THEY DID $\vec{E} = 3 \times 10^9 \text{ V/m}$

SO WHY DON'T THEY?

ENERGY GAIN pE

THERMAL ENERGY $k_B T$

PROB $\sim e^{-pE/k_B T}$

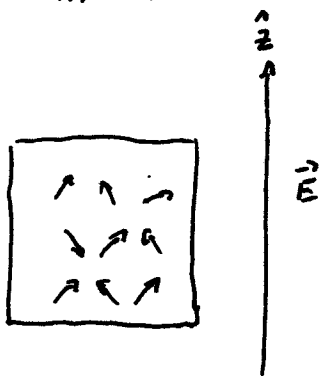
FOR WATER
APPLY 30,000 V/m $\Rightarrow \frac{pE}{k_B T} \sim 10^{-4}$
FOR WATER
E = 90

SMALL ALIGNMENT

MORE THAN ATOMS

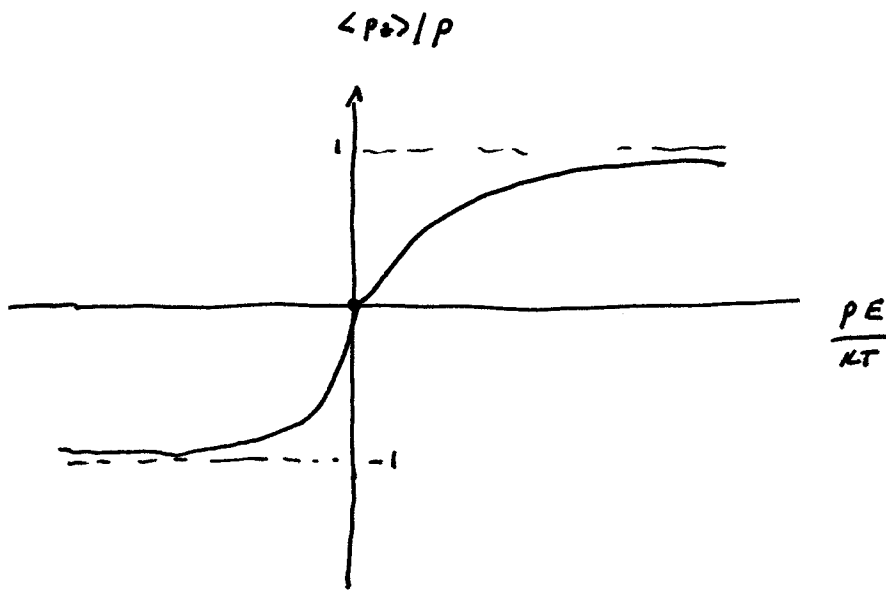
OR NON POLAR DIELECTRICS

THE LANGEVIN EQUATION



some dipoles align

$$\frac{\langle P_z \rangle}{p} = \left[\coth \left(\frac{pE}{kT} \right) - \frac{kT}{pE} \right]$$



CONDUCTORS : free charges

DIELECTRICS : no free charges

free dipoles

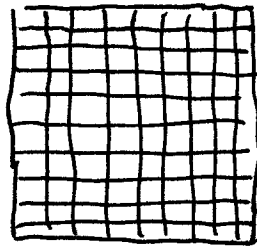
WHAT DO THEY DO?

POLARIZATION

\vec{p} dipole moment of atom or molecule

N number of molecules per unit volume

$\vec{P} = N \vec{p}$ dipole moment per unit volume



surface charge density $\sigma_p = \vec{P} \cdot \hat{n}$

volume charge density $\rho_p = \nabla \cdot \vec{P}$

if \vec{P} is uniform $\rho_p = 0$

$$\sigma_p = \vec{P} \cdot \hat{n}$$

σ_p and ρ_p determine \vec{E} outside

ALIASES:

σ_p polarization

σ_b bound

σ_i induced

$$\vec{\nabla} \cdot \vec{E} = \rho_t / \epsilon_0$$

$$\rho_t = \rho_f + \rho_p$$

$$\nabla^2 V = - \rho_t / \epsilon_0 \quad \text{POISSON'S EQUATION}$$

$$\vec{\nabla} \cdot \vec{E} = \frac{1}{\epsilon_0} (\rho_f + \rho_p)$$

$$\rho_p = - \vec{\nabla} \cdot \vec{P}$$

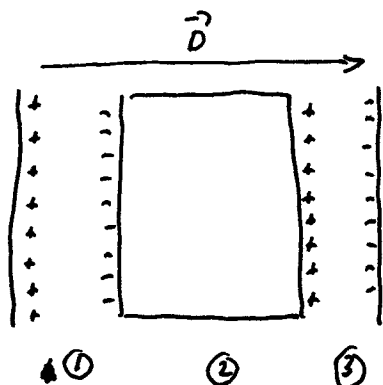
$$\vec{\nabla} \cdot \vec{E} = \frac{1}{\epsilon_0} (\rho_f - \vec{\nabla} \cdot \vec{P})$$

$$\vec{\nabla} \cdot (\epsilon_0 \vec{E} + \vec{P}) = \rho_f$$

$$\vec{\nabla} \cdot \vec{D} = \rho_f$$

lines of \vec{D} start and end on free charges

lines of \vec{E} on all charges



$$\textcircled{1} \quad E = \frac{\sigma_f}{\epsilon_0} \quad D = \sigma_f$$

$$\textcircled{2} \quad E = \sigma_f / \epsilon \quad D = \sigma_f$$

$$\textcircled{3} \quad E = \sigma_f / \epsilon_0 \quad D = \sigma_f$$

$D = \sigma_f$ in $\textcircled{1}$, $\textcircled{2}$, and $\textcircled{3}$

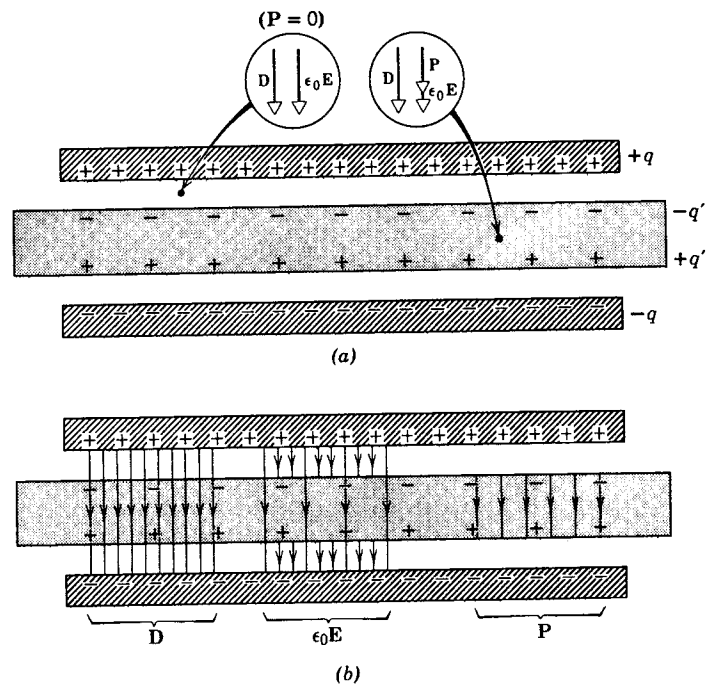
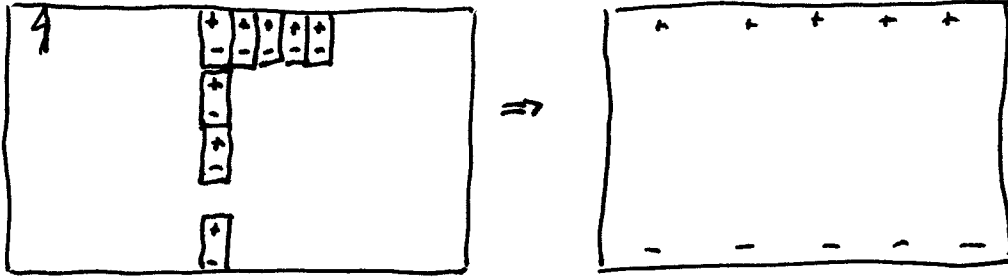


Fig. 30-13 (a) Showing D , $\epsilon_0 E$, and P in the dielectric (*upper right*) and in the gap (*upper left*) for a parallel-plate capacitor. (b) Showing samples of the lines associated with D (free charge), $\epsilon_0 E$ (all charges), and P (polarization charge).

POLARIZATION CHARGES



if dielectric is uniform
 \Rightarrow polarization charge
 on the surface

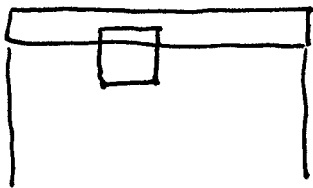
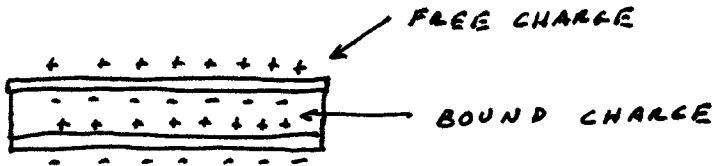
and isotropic

surface charge density

$$\sigma_{pol} = n \vec{p}$$

$$\sigma_{pol} = P$$

surface charge density = polarization inside the dielectric



$$\int \vec{E}' \cdot d\vec{S} = \frac{Q_F}{\epsilon_0}$$

$$E' A = \epsilon_0 (Q_F - Q_b) / \epsilon_0$$

$$E' = \frac{\sigma_F - \sigma_b}{\epsilon_0} = \frac{\sigma_F - P}{\epsilon_0}$$

for low fields
and typical dielectrics

$$\vec{P} = \chi_e \epsilon_0 \vec{E}$$

↑
electric
susceptibility

$$E = \frac{\sigma_F}{\epsilon_0} \left(\frac{1}{\chi_e + 1} \right)$$

↑ the reduction factor

PARALLEL PLATE CAPACITOR

$$V = E d = \frac{\sigma_F}{\epsilon_0} \left(\frac{1}{\chi_e + 1} \right) d$$

$$Q = \sigma_F A$$

$$C = \frac{\epsilon_0 A}{d} (1 + \chi)$$

$$= \frac{\epsilon_0 A}{d} (\kappa)$$

$$\epsilon = (1 + \chi_e) \epsilon_0$$

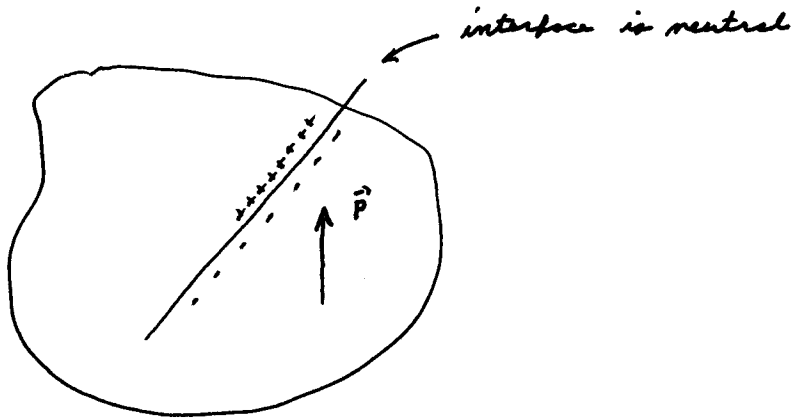
capacitance
increased
by this factor

$$\epsilon = \kappa \epsilon_0$$

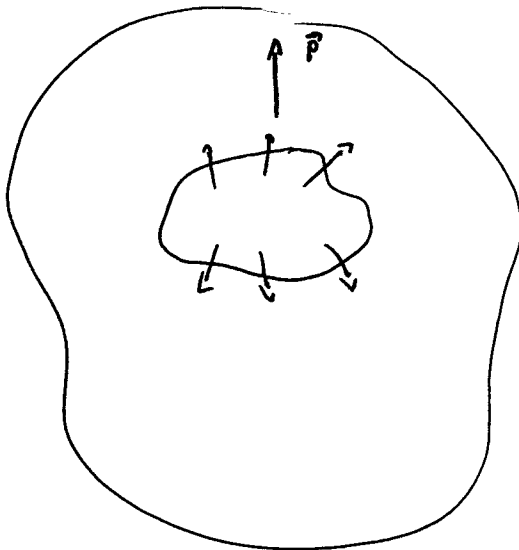
FOR ANY SURFACE

inside or out

$$\sigma_{POL} = \vec{P} \cdot \hat{n}$$



FOR ANY VOLUME



$$\Delta Q_{POL} = - \int_S \vec{P} \cdot d\vec{S}$$

$$\Delta Q_{POL} = \int_V \rho_{POL} dV$$

$$\int_V \rho_{POL} dV = - \int_S \vec{P} \cdot d\vec{S}$$

an integral
a kind of Gauss's Law
for \vec{P} and ρ_{POL}

$$\rho_{POL} = - \nabla \cdot \vec{P}$$

$$\nabla \cdot \vec{E} = \rho_T / \epsilon_0$$

$$\nabla \cdot \vec{P} = -\rho_{POL}$$

if \vec{P} is not uniform,
then there will be a
net polarization charge
density

perfectly

real charge

ρ_{POL} is just
JUST REMINDS US
WHERE IT CAME
FROM

ELECTROSTATICS WITH DIELECTRICS

$$\vec{\nabla} \cdot \vec{E} = \frac{\rho_T}{\epsilon_0} \quad \text{FUNDAMENTAL EQUATION}$$

$$\rho_T = \rho_{\text{FREE}} + \rho_{\text{POL}} = \rho_{\text{FREE}} - \vec{\nabla} \cdot \vec{P}$$

$$\vec{\nabla} \cdot \vec{E} = \frac{1}{\epsilon_0} (\rho_{\text{FREE}} - \vec{\nabla} \cdot \vec{P})$$

$$\vec{\nabla} \cdot \left(\vec{E} + \frac{\vec{P}}{\epsilon_0} \right) = \frac{\rho_{\text{FREE}}}{\epsilon_0}$$

$$\vec{\nabla} \times \vec{E} = 0 \quad \text{is still equal to zero}$$

$$\vec{P} = \kappa \vec{E}$$

$$\vec{\nabla} \cdot ((1+\kappa) \vec{E}) = \vec{\nabla} \cdot (\kappa \vec{E}) = \frac{\rho_{\text{FREE}}}{\epsilon_0}$$

NOTHING NEW

CONVENIENT WHEN WE KNOW ρ_{FREE} AND \vec{P}

if κ is constant, we can take it outside

$$\vec{\nabla} \cdot \vec{E} = \frac{\rho_{\text{FREE}}}{\epsilon}$$

if it varies in space, interesting effects occur

MAXWELL INTRODUCED \vec{D}

$$\vec{D} = \epsilon_0 \vec{E} + \vec{P}$$

$$\vec{\nabla} \cdot \vec{D} = \rho_{FREE}$$

$$\vec{\nabla} \times \vec{E} = 0$$

in general $\vec{\nabla} \times \vec{D} \neq 0$

no potential for \vec{D}

in high symmetry cases,
 \vec{D} works well

NOT ENOUGH TO SOLVE!

MUST ADD SOMETHING

$$\vec{D} = \epsilon \vec{E} = \epsilon_0 (1 + \chi) \vec{E} = \kappa \epsilon_0 \vec{E}$$

ϵ is called the permittivity

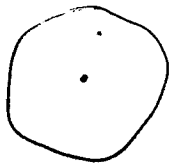
χ electric susceptibility

κ dielectric constant

ϵ_0 permittivity of free space

\vec{D} is not fundamental!

it just includes the effects of matter



mostly empty
space

WHY DOES A COMB PICK UP LITTLE
 PIECES OF PAPER?



POINT
 FOR A DIPOLE \vec{p} IN AN INHOMOGENEOUS FIELD

$$\vec{F} = \vec{p} \cdot (\vec{\nabla} \vec{E})$$

$$F_x = \vec{p} \cdot \vec{\nabla} E_x$$

$$F_y = \vec{p} \cdot \vec{\nabla} E_y$$

$$F_z = \vec{p} \cdot \vec{\nabla} E_z$$

HOW DOES THE FORCE SCALE WITH \vec{E} ?

$$\vec{p} = \alpha \vec{E}$$

$$p \sim E$$

$$\vec{\nabla} E \sim E$$

$$F \sim E^2$$

NO FORCE IN A UNIFORM FIELD

THE CANONICAL PROBLEMS

OBJECTS

SOURCES

dielectric

sphere

uniform field

cylinder

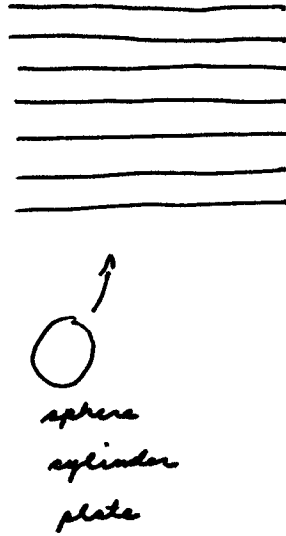
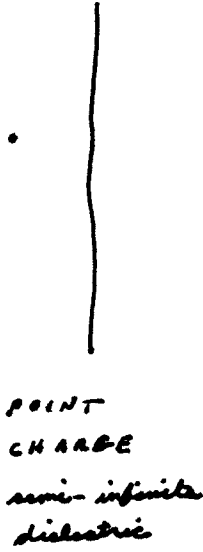
point charge

plane

line charge



CANONICAL PROBLEMS



SHOW FALSTAD.COM

solve Maxwell's equations

images

Laplace's eqn KNOWN VOLTAGES

Poisson's eqn

<http://www.falstad.com/vector3de/>

This applet is an electrostatics demonstration which displays the electric field in a number of situations. You can select from a number of fields and see how particles move in the field if it is treated as either a velocity field (where the particles move along the field lines) or an actual force field (where the particles move as if they were charged particles). This helps you visualize the field. When you start the applet, you will see 500 particles moving in a point charge field. By default the particles are treating the field as a *velocity* field, which means that the field vectors determine how fast the particles are moving and in what direction. In this case, the particles just move toward the center. The velocity of all the particles at a certain point on the grid is always the same. If the field is a *force* field, then the field vectors determine the acceleration of the particles, but their velocity may vary depending on where they started.

The **Field Selection** popup will allow you to select a vector field.

The choices that we looked at in class are:

conducting sphere + pt: A conducting sphere near a point charge. The size of the sphere, the separation between it and the point charge, and the potential of the sphere are all adjustable. By default the sphere is grounded.

charged sphere + pt: A charged sphere near a point charge. This is provided to show the difference between a charged sphere and a conducting sphere. (The main difference is that the electric field lines are always perpendicular to the surface of the conducting sphere, whereas this is not true with a charged sphere. This is easier to see with a Y Slice.) By default the sphere has no charge, but this can be adjusted to a positive or negative value.

cyl + line charge: A conducting cylinder near a line charge.

conducting sphere in field: A grounded conducting sphere in a uniform external field.

dielec sphere in field E: This is the electric field of a dielectric sphere in a uniform external field. The size of the sphere and the dielectric strength are adjustable. A dielectric is an insulating material whose atoms are polarized in response to an external field; this causes the field to be weaker inside the dielectric.

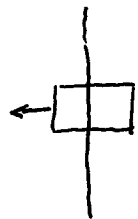
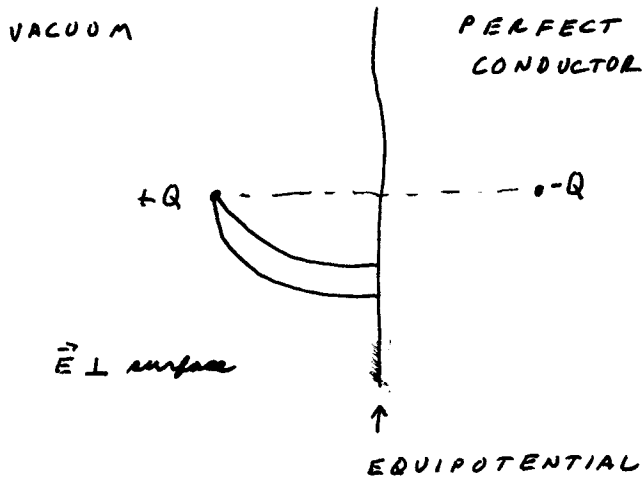
cylinder in field: A grounded conducting cylinder in a uniform external field.

dielec cyl in field E: This is the electric field of a dielectric cylinder in a uniform external field. The size of the cylinder and the dielectric strength are adjustable.

dielec boundary E: This is the electric field of a point charge near a dielectric boundary. The point charge is located outside of the dielectric by default; so the dielectric is the area below the boundary plane. The location of the point charge and the dielectric strength are adjustable.

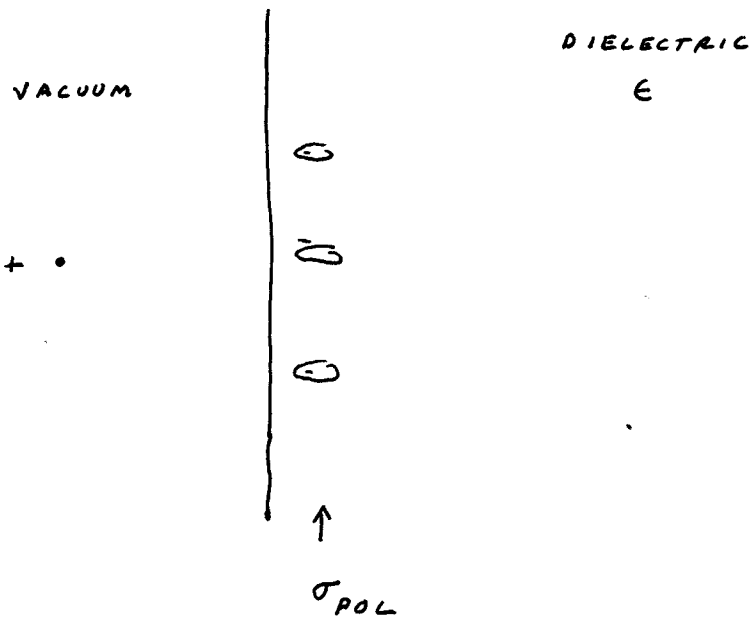
conducting plane + pt: This is the electric field of a point charge near a conducting boundary.

IMAGES IN DIELECTRICS



$$E \cdot A = \sigma A / \epsilon_0$$

$$E = \frac{\sigma}{\epsilon_0}$$



OUTSIDE

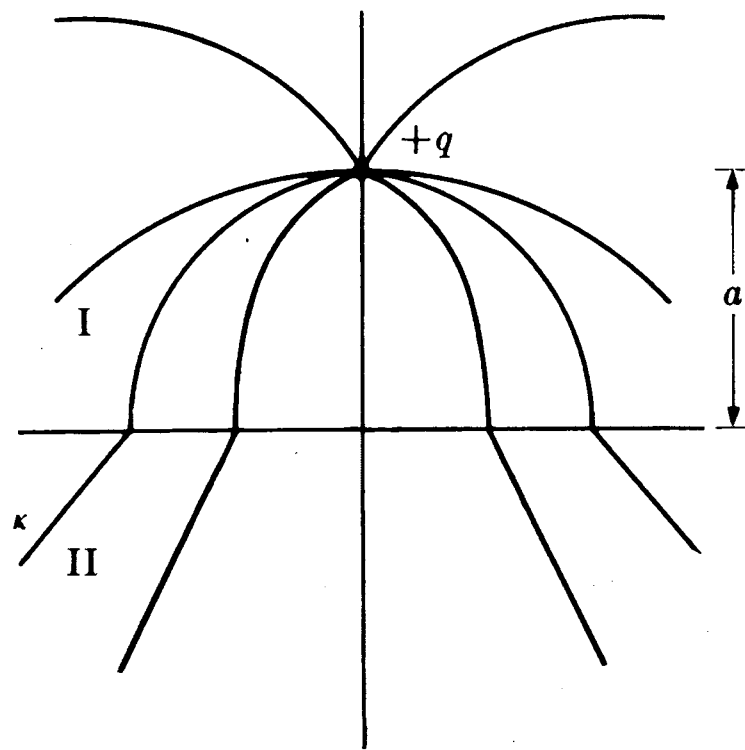
Q •

$$Q' = \frac{\kappa_1 - \kappa_2}{\kappa_1 + \kappa_2} Q$$

INSIDE

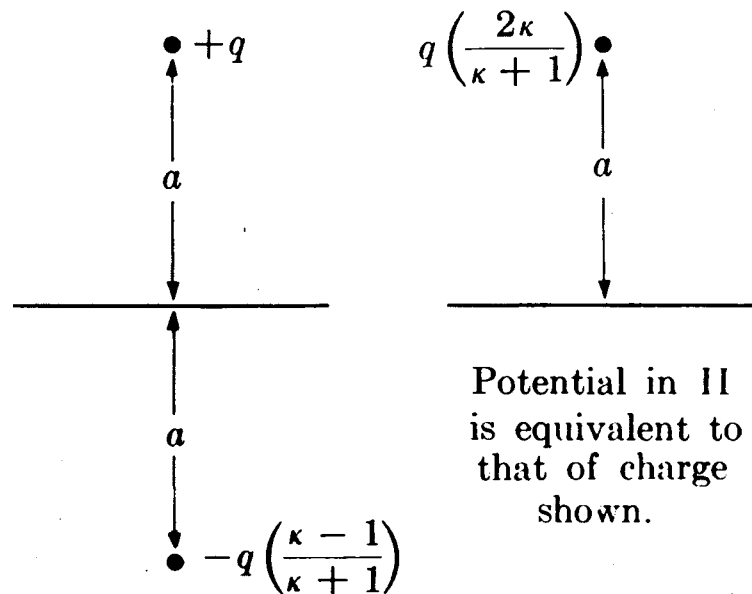
•
↑
Q + Q''

$$Q'' = \frac{2\kappa_2}{\kappa_1 + \kappa_2}$$



Actual configuration.
(Lines of \mathbf{D} shown.)

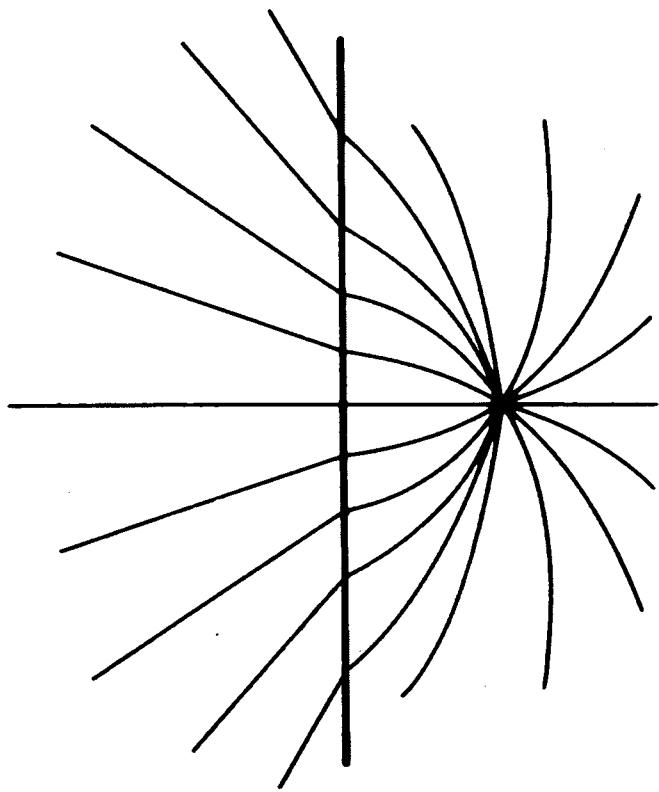
(a)



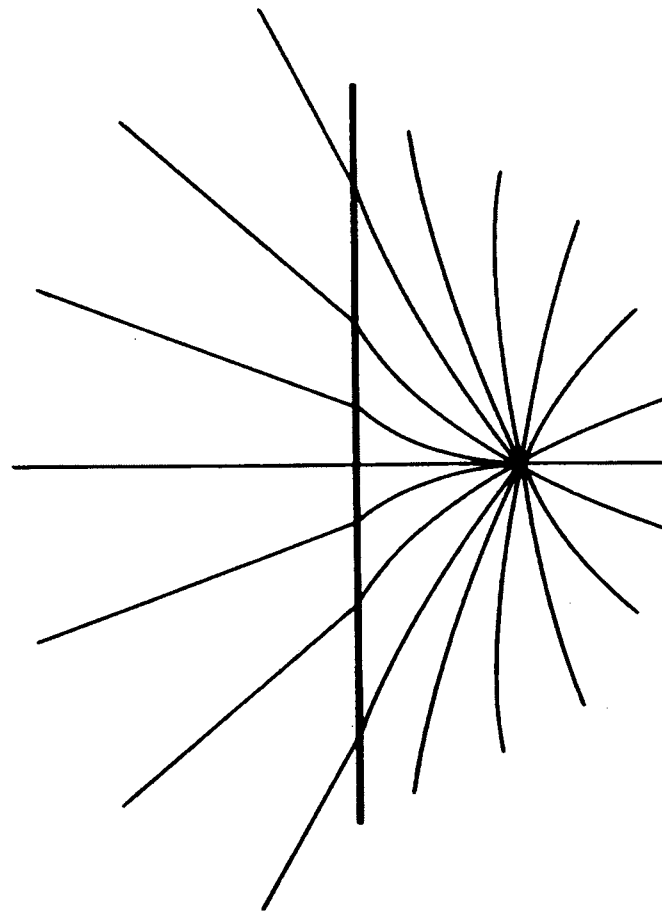
Potential in I is equivalent
to that of charges shown.

(b)

FIG. 3-3. Point charge and "dielectric half-space." (a) represents the actual physical system of a charge $+q$ at a distance a from a dielectric half-space of specific inductive capacity κ . (b) is a system of images representing the configuration: the left-hand side of the distribution (b) is a system of charges which gives the correct field distribution in region I; the right-hand part gives the correct field distribution in region II.



$\epsilon_2 > \epsilon_1$



$\epsilon_2 < \epsilon_1$

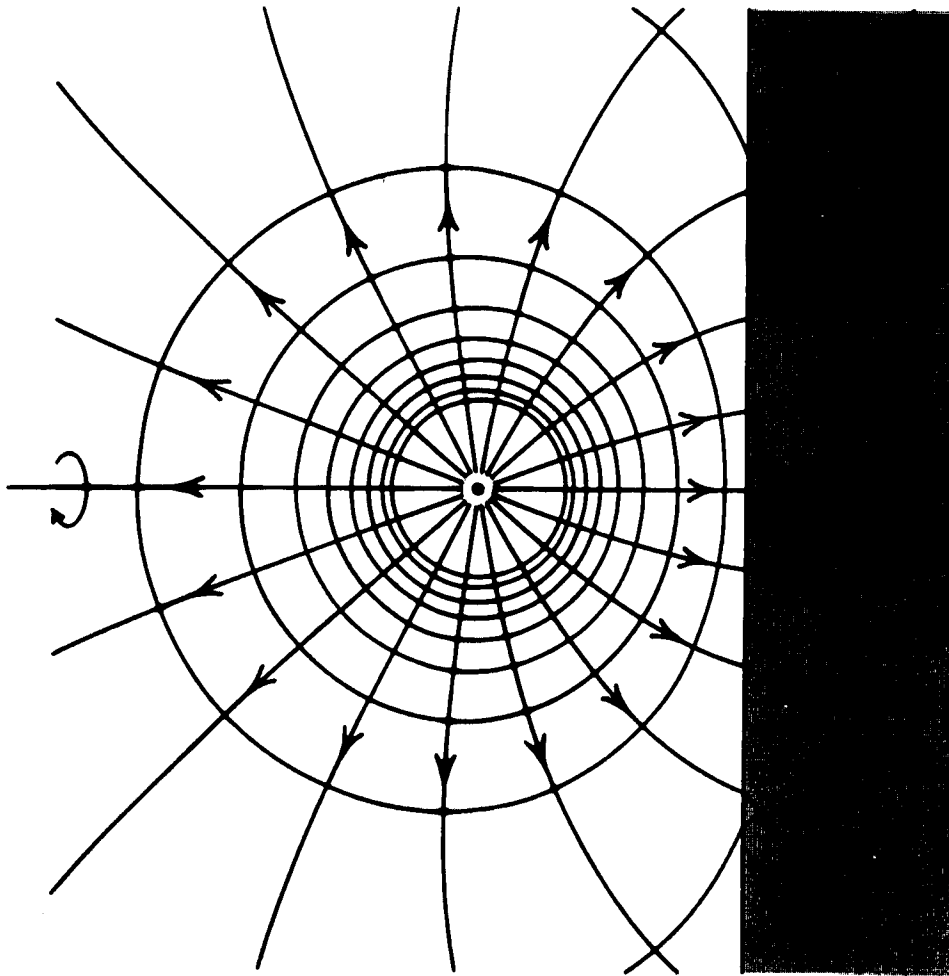


Figure 4-15. Lines of D (identified by arrows) and equipotentials for a point charge near a dielectric. As previously, equipotential surfaces are generated by rotating the figure about the axis indicated by the curved arrow. Equipotentials and lines of D near the point charge are not shown.

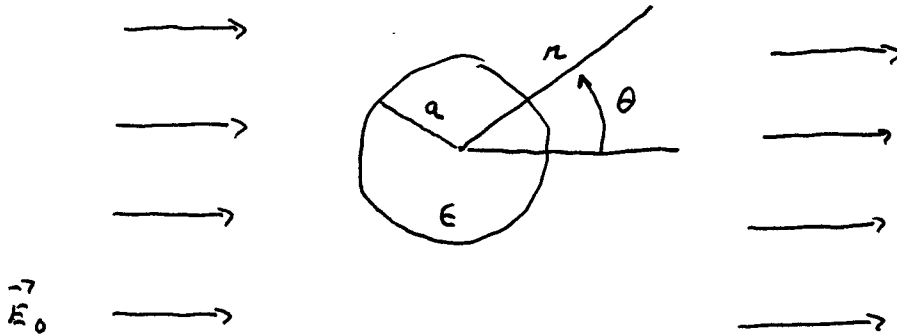
the same medium 1 on both sides of the interface, the original charge Q , and a charge

$$Q' = \frac{\epsilon_{r1} - \epsilon_{r2}}{\epsilon_{r1} + \epsilon_{r2}} Q \quad (4-55)$$

at the image position. The field in medium 2 is the same as if medium 2 extended on both sides of the interface and the original charge Q were replaced by

$$Q'' = \frac{2\epsilon_{r2}}{\epsilon_{r1} + \epsilon_{r2}} Q \quad (4-56)$$

DIELECTRIC SPHERE IN AN APPLIED FIELD



$$\nabla^2 V = 0$$

$$\nabla^2 V_{in} = 0$$

$$\nabla^2 V_{out} = 0$$

$$V_{in} = \sum_{l=0}^{\infty} a_l r^l P_l(\cos \theta)$$

$$V_{out} = \sum_{l=0}^{\infty} [b_l r^l + c_l r^{-(l+1)}] P_l(\cos \theta)$$

BCs

COMPONENT OF \vec{E}

TANGENTIAL CONTINUOUS ACROSS BOUNDARY

$$-\frac{1}{a} \left. \frac{\partial V_{in}}{\partial \theta} \right|_{r=a} = \frac{1}{a} \left. \frac{\partial V_{out}}{\partial \theta} \right|_{r=a}$$

NORMAL COMPONENT OF \vec{D} CONTINUOUS

$$-\epsilon \left. \frac{\partial V_{in}}{\partial r} \right|_{r=a} = - \left. \frac{\partial V_{out}}{\partial r} \right|_{r=a}$$

E_{TAN} BC:

$$A_{l1} = -E_0 + \frac{C_1}{a^3}$$

$$A_L = \frac{C_L}{a^{2L+1}} \quad \text{for } L \neq 1$$

\vec{D}_L BC:

$$\epsilon A_1 = -E_0 - 2 \frac{C_1}{a^3}$$

$$\epsilon L A_L = -(L+1) \frac{C_L}{a^{2L+1}}$$

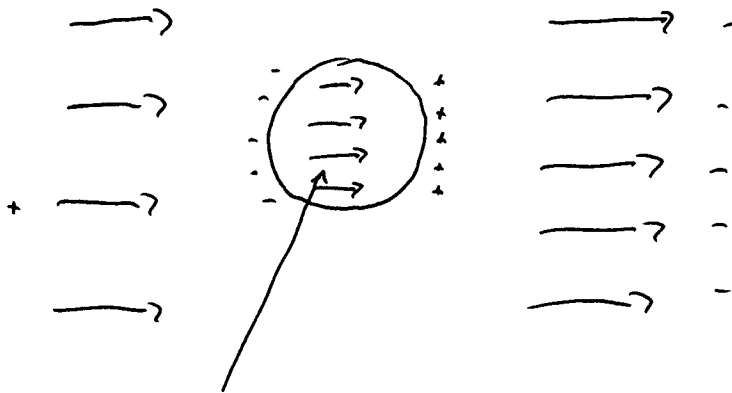
$$\Rightarrow A_L = C_L = 0 \quad \text{for all } L \neq 1$$

$$A_1 = - \left(\frac{3}{2 + \epsilon} \right) E_0$$

$$C_1 = \left(\frac{\epsilon - 1}{\epsilon + 2} \right) a^3 E_0$$

$$V_{in} = - \left(\frac{3}{2 + \epsilon} \right) E_0 r \cos \theta$$

$$V_{out} = - E_0 r \cos \theta + \left(\frac{\epsilon - 1}{\epsilon + 2} \right) E_0 \left(\frac{a^3}{r^2} \right) \cos \theta$$



UNIFORM \vec{P} INSIDE

$$\vec{E}_{inside} \text{ due to } \vec{P} = \left(\frac{3}{2 + \epsilon} \right) E_0$$

OUTSIDE UNIFORM \vec{E}

PLUS

DIPOLE

$$p = \left(\frac{\epsilon - 1}{\epsilon + 2} \right) a^3 E_0$$

$$\vec{P}_{in} = (\epsilon - 1) \vec{E} = (\epsilon - 1) \left(\frac{3}{2 + \epsilon} \right) E_0$$

$$\vec{\nabla} \cdot \vec{P}_{in} = 0$$

$$\vec{P} \cdot \hat{m} = \sigma_{pol} = \left(\frac{3}{2 + \epsilon} \right) (\epsilon - 1) E_0 \cos \theta$$

SPHERICAL
CAVITY

OPPOSITE
POL σ_{pol}

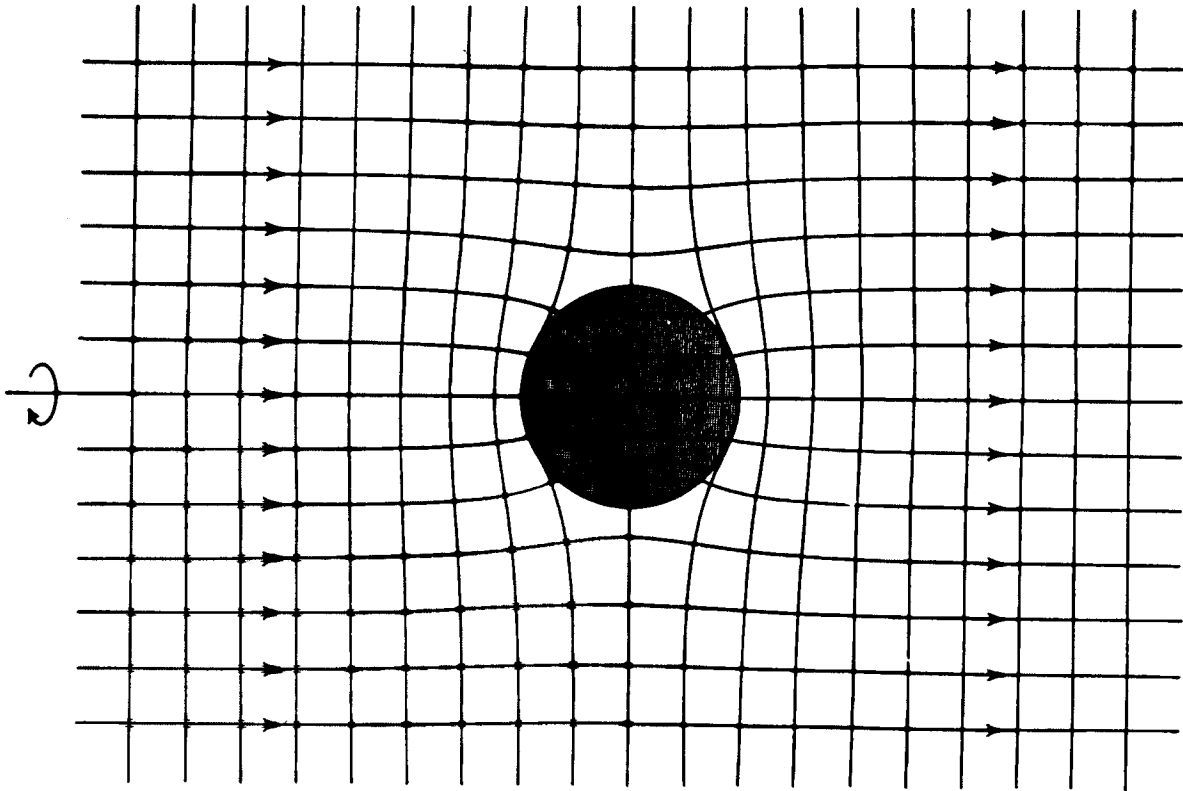


Figure 4-24. The field near a *dielectric sphere* ($\epsilon_r = 3$) in a uniform electric field. The lines of D (indicated by arrows) crowd into the sphere as shown, with the result that D is larger inside than outside. Since there is no free charge at the surface of the sphere, the lines of D neither originate nor terminate there, and they are continuous across the boundary. The equipotentials spread out inside, corresponding to a *lower* electric field intensity E . The electric field intensity E is discontinuous at the surface, and the density of lines of force is lower inside than outside. As in the conducting sphere, the field is hardly disturbed at distances larger than one radius from the surface. The field inside is uniform. The origin is chosen at the center of the sphere and the polar axis used in the calculation points to the right.

CONDUCTING SPHERE

$$r = a \quad V = 0$$

$$r = \infty \quad V = -E_0 z = -E_0 r \cos \theta$$

only A_1 and C_1

$$A_1 = -E_0$$

$$C_1 = -A_1 a^3 = E_0 a^3$$

$$V = -E_0 r \cos \theta + B \frac{\cos \theta}{r}$$

\uparrow
 $E_0 a^3$

$$V = -E_0 r \cos \theta + E_0 a^3 \frac{\cos \theta}{r}$$

\uparrow
APPLIED
FIELD

\uparrow
OPPOSING
DIPOLE

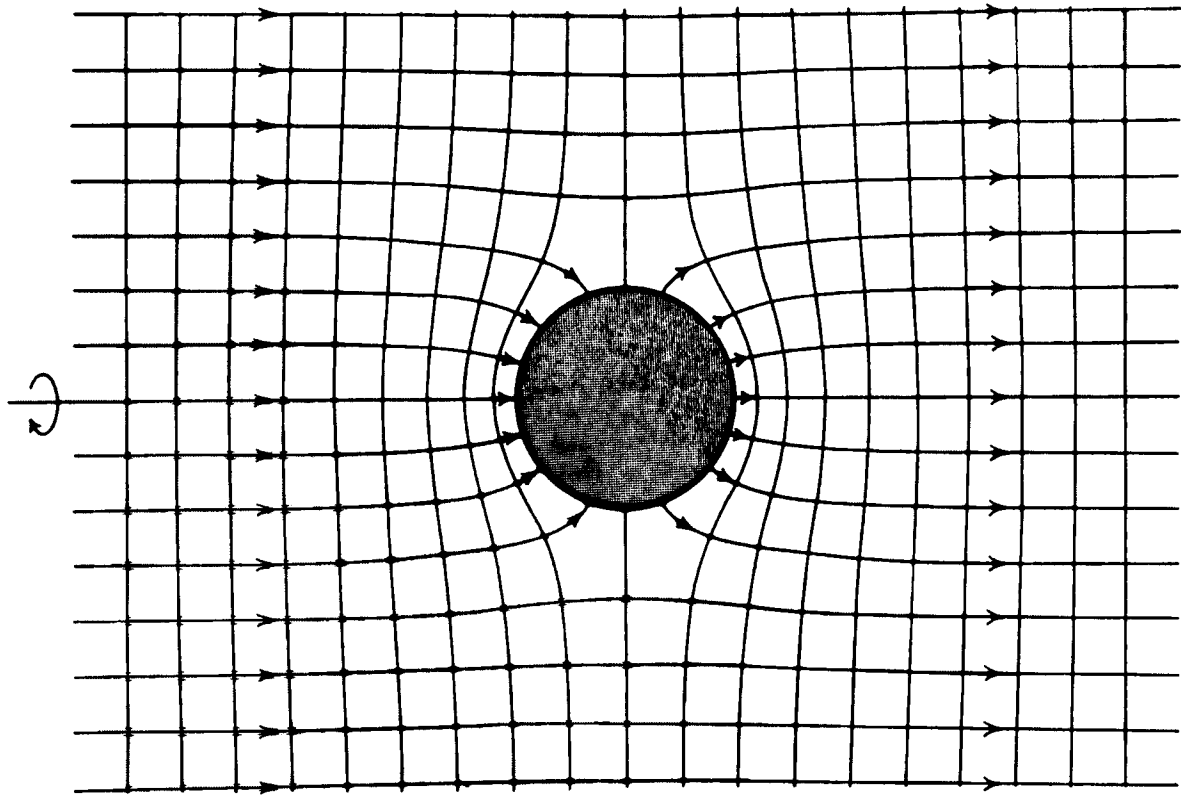


Figure 4-22. Lines of force (indicated by arrows) and equipotentials for a *conducting sphere* in a uniform electric field. The lines of force are normal at the surface of the sphere, and there is zero electric field intensity inside. Observe that the field is hardly disturbed at distances larger than one *radius* from the surface of the sphere. The origin is at the center of the sphere and the polar axis used in the calculation points to the right.

